C harge-T ransfer E xcitations in the M odel Superconductor H gB a_2 C uO $_{4+}$

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We report a Cu K -edge resonant inelastic x-ray scattering (R IX S) study of charge-transfer excitations in the 2-8 eV range in the structurally simple compound $HgBa_2CuO_{4+}$ at optim all doping ($T_c = 96.5$ K). The spectra exhibit a signi cant dependence on the incident photon energy which we carefully utilize to resolve a multiplet of weakly-dispersive (< 0.5 eV) electron-hole excitations, including a mode at 2 eV. The observation of this 2 eV excitation suggests the existence of a rem nant charge transfer gap deep in the superconducting phase. Quite generally, our data demonstrate the importance of exploring the incident photon energy dependence of the R IX S cross section.

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A pivotal challenge in the study of correlated electron systems is to understand the nature of their electronic excitations. Compared to our know ledge of magnetic and single quasi-particle excitations, rem arkably little is known about the hierarchy and momentum dependence ofelem entary collective charge excitations in doped M ott insulators such as the cuprate superconductors. The reason for this limitation has been the lack of a suitable spectroscopic technique. O ptical spectroscopy probes the dipole-allowed electron-hole pair excitations, but is lim ited to zero m om entum transfer [1], while electron energy loss spectroscopy (EELS) is surface sensitive and strongly a ected by multiple scattering e ects at large m om entum transfers [2, 3, 4, 5]. The relatively new technique of resonant inelastic x-ray scattering (R IX S), on the other hand, has the potential both to probe such excitations with bulk sensitivity and to yield momentum -resolved inform ation throughout the Brillouin zone [6].

Previous RIXS studies focused predom inantly on the undoped insulators and revealed an excitation with an energy of 2 eV [7, 8, 9], consistent with optical spectroscopy [1]. This charge-transfer (CT) excitation is associated with dipole transitions from the top of the valence, or Zhang-Rice singlet (ZRS) band to the unoccupied conduction band. In La_2CuO_4 [9], the excitation was found to disperse strongly (1 eV) along [,0] and was quickly suppressed along [,], while in Ca₂CuO₂Cl₂ [8] it was observed to disperse by 0:7 eV along [,0], but by 1:6 eV along [,]. Finally, in Sr₂CuO₂C₂, it was found to shift very weakly and to lose de nition along [2;] [7]. In each case, RIXS also revealed additional broad excitations at higher energy. The strongest such feature, located at 6 7 eV, is commonly accepted to be a local m olecular orbital excitation, where an electron is excited

from a bonding to an antibonding state on a single CuO₄ plaquette [10]. An additional, weakly dispersing mode was observed near 4 eV in La₂CuO₄ [9]. Two important issues that remain to be resolved are the apparent material dependent di erences and the evolution with doping of the low-energy CT excitations.

W e present R IX S m easurem ents for optim ally-doped $HqBa_2CuO_{4+}$ (Hg1201) at high-symmetry positions along [;0] and [;]. Hg1201 is a model superconductor due to its high value of T_c (highest am ong all single-layer cuprates), simple tetragonal structure, relatively large spacing between CuO₂ planes, and the absence of structural features characteristic of other cuprates, such as superstructure m odulations and Cu-O chains [11]. Through a careful analysis of the incident energy dependent R IX S spectra, we are able to identify a 2 eV CT excitation and to determ ine an upper bound of 0.5 eV for its dispersion. The observation of this mode suggests the existence of a remnant CT gap in optimally-doped Hg1201. In addition, we are able to resolve weakly-dispersive excitations at 3, 4, 5, 6, and 7 eV .W e also present new results for La₂CuO₄ which reveal that this multiplet structure is present already in the undoped M ott insulators. To account for this rich structure, we suggest that in addition to a ZRS contribution, it is necessary to consider CT processes that involve non-bonding 0 2p bands with a sm alladm ixture of Cu 3d levels.

A large (20 mm^3) H g1201 single crystal was grown by the ux method at Stanford University [12]. It was heat-treated in an oxygen atm osphere to achieve optim al doping, and magnetom etry indicated $T_c = 96.5 \text{ K}$ (onset), as shown in Fig. 1(a). Initial characterization at the Stanford Synchrotron R adiation Laboratory, with 12 keV x-rays at beam line 7-2, revealed a mosaic of 0.04

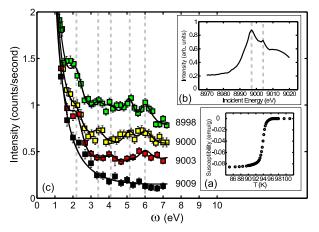


FIG.1: Hg1201: (a) M agnetic susceptibility. (b) X -ray absorption spectrum monitored by uorescence yield. (c) Zonecenter RIXS spectra at four incident energies, shifted below 9009 eV by 0.2 counts/s relative to each other. Solid lines are ts described in the text. Vertical lines indicate (b) the two interm ediate states where a resonant enhancem ent is observed in RIXS and (c) distinct electron-hole excitations.

(FW HM). RIXS was performed on the undulator beam line 9ID B at the Advanced Photon Source, with incident photon energy (E_i) set to values near the C u K -edge using a Si(333) double m onochrom ator. A spherical, diced Ge(733) analyzer was used, and the overall energy resolution was 300 m eV (FW HM). The experim ent was perform ed around the weak (2,0,1) and (3,0,0) re ections. The incident photon polarization was perpendicular to the vertical scattering plane and within the CuO₂ planes. Figure 1 (b) shows the x-ray absorption spectrum for our crystal. The main edge (8998 eV) and satellite peak (9003 eV) correspond to the two distinct 1s ! 4p transitions responsible for the resonant enhancem ent present in the RIXS spectra. The La₂CuO₄ crystal had a N eel tem perature of $T_N = 320 \text{ K}$ [13] and was measured with polarization perpendicular to the CuO₂ planes, consistent with previous work [9]. All measurements were carried out at room temperature. In this Letter, we specify the in-plane component of the reduced wave vector q and use units with lattice constant a 1 and h 1. The energy transfer is de ned as $! = E_i \quad E_f$.

Figure 1 (c) shows H g1201 zone-center spectra at four values of E_i . For $E_i = 8998 \text{ eV}$, we observe a peak at ! = 22 eV together with two less intense, but clearly resolvable features at 5.2 eV and 6.0 eV, and a spectral weight enhancement at intermediate energy transfers. By gradually tuning E_i to higher energies, two additional features, centered at 3.4 eV and 4.1 eV, sequentially stand out when compared to the featureless \background" spectrum at $E_i = 9009 \text{ eV}$. We will refer to these features as $\langle 2 \text{ eV}$, " $\langle 3 \text{ eV}$," $\langle 4 \text{ eV}$," $\langle 5 \text{ eV}$," and $\langle 6 \text{ eV}$," according to their approximate peak positions. We emphasize that, when viewed as a second-order process, the R IX S cross section, as in the case of resonant R am an scattering [14], depends on both ! and E_i [6].

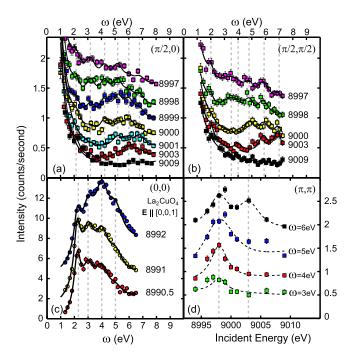


FIG. 2: Hg1201 RIXS spectra at (a) (=2;0) and (b) (=2; =2). The data are shifted below 9009 eV by 0.2 counts/s relative to each other. The solid lines are ts described in the text. (c) La_2CuO_4 zone-center sprectra; 8991 and 8992 eV data are shifted vertically. (d) Hg1201 E_i-dependence at (,) for several energy transfers.

The relative strength of the excitations also is a function of wave vector. Figure 2 contains results for (a) (=2,0) and (b) (/2,/2). The 2 eV mode rapidly decreases in strength toward the zone boundary, similar to previous results for La_2CuO_4 [9]. On the other hand, the higher-energy modes gain in intensity toward the zone boundary and the multiplet structure becomes more pronounced. A part from the 2 eV and 3 eV features, which are not discernible at (,0), and (,), respectively, the multiplet structure in the 2-6 eV range is similar to the zone center result Fig. 1 (c)]. We focus on the velow estlying features, but note that some spectra exhibit additional features at 7 eV and 9 eV (not shown).

A lthough R IX S m easures the electron-hole pair dynam ics rather than the properties of a single hole quasiparticle, the multiplet structure resem bles valence band photoem ission results for $Sr_2CuO_2Cl_2$, for which separate bands with rather di erent mixing between Cu 3d and O 2p orbitals have been associated with the signi cant intensity variations with momentum and energy [15, 16].

A reasonable estim ate of the peak positions can be obtained already by visual inspection of the data. To arrive at a more precise estimate, at each wavevector we not the E_i = 9009 eV data to a Lorentzian centered at ! = 0, and then used this as \background" in a simultaneous t of all the other spectra to a set of Lorentzians with E_i-independent peak positions and E_i-dependent am plitudes. The description of some of the spectra required an additional linear contribution. The peaks are broader

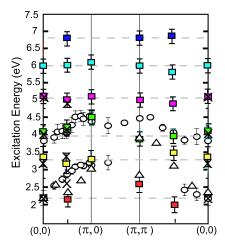


FIG. 3: Dispersion of CT excitations for optim ally-doped H g1201 (squares), com pared with previous results below 6 eV for $Ca_2CuO_2Cl_2$ (triangles) [8, 20] and La_2CuO_4 (circles) [9], and new data for La_2CuO_4 (crosses).

than our resolution of 0.3 eV, and in the ts of Figs. 1 and 2 the peak widths were xed at a value of 0.8 eV[17, 18, 19] based on their apparent widths.

As can be seen from Fig. 3, the di erence between the excitation energies at (0,0) and the zone boundary is relatively small for all modes, within 0.5 eV. Rather than observing a single highly dispersive mode below 4 eV, as found previously for the M ott insulators La₂C uO₄ and Ca₂CuO₂C₂, we discern two separate and much less dispersive branches [20]. Because of the signi cant E_i dependence observed here for Hg1201, it appears possible that two weakly dispersive low -energy modes already are present in the undoped M ott insulators, which could unify the seem ingly disparate behavior of di erent com pounds [7, 8, 9]. To test this possibility, we perform ed a new measurement for La_2CuO_4 [at (0,0), shown in Fig. 2 (c), and also at (=2;0)], and a reanalysis of the zonecenter result of R ef. [9] along the lines discussed above, which suggests that this is indeed the case. The data indicate four features below 6 eV at energies very sim ilar to those for H g1201 (see F ig. 3). It therefore seems very likely that the strong dispersion observed in Refs. [8,9] stem s from an e ective adm ixture of the two low estlying modes. Nevertheless, from our result at (=2;0) it appears that the 2 eV m ode in the M ott insulator has a larger dispersion than in superconducting H g1201, consistent with recent theory [21] and experim ent [22].

Recent R IX S studies of doped cuprates suggest an interesting doping dependence of the spectral features [22, 23, 24]. A continuum of intensity was found to emerge below 2 eV with increasing doping for $La_2 \times Sr_x CuO_4$ [22, 23], and the lowest-energy CT excitation (at 2 eV) is completely suppressed for x = 0:17 [23]. Due to the relatively strong \elastic tail" we were not able to probe the region well below 2 eV in Hg1201 with the present energy resolution. However, in contrast to the observation for $La_2 \times Sr_x CuO_4$, which appears to be consistent with optical spectroscopy [1], we clearly resolve a wellde ned low-energy feature at 2 eV. It rapidly decreases in strength away from the zone center, but can still be traced up to the zone boundary, with a net dispersion no greater than 0.5 eV. We note that it is unlikely to be a d d type excitations. The latter lie below 2 eV [26,27] and are expected to be much weaker at the K-edge than at the L [26] and M edges [27]. Furtherm ore, at the C u K-edge, one m ight expect such excitations to be signi cant at the pre-edge ($E_i = 8985 \text{ eV}$, 1s 3d transition), but we did not observe a \2eV " feature at this incident energy. Therefore, optim ally doped H g1201, the singlelayer cuprate with the highest T_c , exhibits a rem nant C T gap. It would be very valuable to extend initial results for the optical conductivity of H g1201 [25].

The most signi cant feature for $E_i = 9003$ eV is the non-dispersing 6 eV mode, which is very likely the (local) molecular orbital excitation from the bonding (predom inantly 3d⁹) to the antibonding state (predom inantly 3d¹⁰L), consistent with a system atic study am ong cuprates of the bond-length dependence of the energy of this feature (d_{C u 0} = 1.9396 A at T = 300 K for our crystal) [10]. As further indication of its local character, we note that this excitation resonates at both $E_i =$ 8998 eV and 9003 eV, as can be seen from Fig. 2(d). These two resonance energies are the nal states in the x-ray absorption spectra of Fig. 1(b), and they correspond to di erent interm ediate states in the RIXS process, one which is well-screened (8998 eV; predom inantly 1s3d¹⁰L4p) and the other poorly-screened (9003 eV; predom inantly $1 \pm 3d^9 4p$). The double-resonance behavior has been captured using the Anderson impurity model of a single CuO_4 plaquette [18, 19], thus enforcing the conclusion that these excitations are local.

W ith the exception of the 2 eV feature, the Hg1201 spectra for ! < 6 eV exhibit a di erent resonant behavior as they are much stronger at $E_i = 8998$ eV than at 9003 eV [Fig. 2 (d)]. This suggests that the corresponding excitations have a more signi cant overlap with the well-screened (3d¹⁰L) than with the poorly-screened (3d⁹) interm ediate states. In this scenario, the resultant screening can have both local and nonlocal contributions, as

rst suggested in the context of C u 2p core-level photoem ission [28, 29, 30, 31, 32]. In nonlocal screening, a hole residing on the surrounding oxygen ligand is C oulom brepelled by the 1s core hole on the central C u site and delocalizes to a neighboring C uO₄ plaquette. The delocalized hole can either form a ZRS with a neighboring C u, orm ove to non-bonding O 2p orbitals (2p, 2p and 2p_z). D ue to the planar polarization in our experiment, CT transitions to purely $2p_z$ orbitals are suppressed. Therefore, there are three nonlocalm odes that m ay contribute to the observed spectra. In local screening, on the other hand, the single-C u site Anderson im purity m odel calculations [18, 19] reveal that the nal state has nearly pure O 2p character due to the strong core hole potential

on the same plaquette. Unlike for the nonlocal modes, the ligand hole does not m igrate to a neighboring CuO₄ plaquette. For in-plane polarization, there should be two local modes that correspond to CT transitions to the two local in-plane O 2p orbitals (2p ;2p). Consequently, we arrive at ve candidate modes for the four observed features below 6 eV. Due to the intrinsic broadening and the relatively high density of modes, we m ight not be able to discern all of them.

InitialEELS m easurem ents of Sr₂CuO₂C b indicated a single CT gap excitation of 2 eV with a large dispersion of 1.5 eV along [;] [2]. However, a more recent highresolution (115 m eV) study revealed a multiplet structure in this M ott insulator [3, 4], analogous to our present observations. By extending theoreticalm odels to include a complete set of Cu 3d and O 2p states, the multiplet structure was found to be consistent with a prediction of multiple charge-transfer type excitations, originating either locally or nonlocally. Recent models of the Cu K -edge R IX S processes, based on a multi-band Hubbard model approach, show that at half-lling a total of four transitions appear below 6 eV [33, 34, 35]. In principle, the addition of holes perm its additional transitions into the ZRS band which may not be easily discernible. At optim al (hole) doping, the theoretical prediction for the R IX S spectra is remarkably sim ilar to the result at half-

lling for a reasonably large choice of C u onsite repulsion [35]. This is consistent with our experimental ndings for H g1201 and La_2CuO_4 .

In conclusion, we have measured electron-hole pair excitations in the 2-8 eV range along [;0] and [;] in optimally-doped HgBa₂CuO₄₊ using resonant inelastic x-ray scattering. By carefully utilizing the incident photon-energy dependence of the cross section, we discern a multiplet of excitations, and we establish an upper bound of 0.5 eV for the dispersion of all excitations. O ur observation of an excitation at 2 eV in this veryhigh-T_c material is in surprising contrast with previous

ndings for (La,Sr)2CuO4. One possible reason for this di erence may be the presence of signi cant quenched disorder in close proxim ity to the Cu-O sheets in the latter m aterial [11]. W hile superconducting H gB a₂C uO ₄₊ is expected to have signi cant spectral weight at lower energies, our nding suggests the existence of a rem nant charge-transfer gap. Now that sizable $HgBa_2CuO_{4+}$ crystals have become available, we plan to complement the present work on this model superconductor using other experim ental techniques in order to fully elucidate materials speci c di erences among the cuprate superconductors. Our partial reinvestigation of La₂CuO₄ revealed them ultiplet structure already present in the M ott insulating parent compounds, and it indicates that the dispersion of the 2 eV mode is smaller than previous estim ates. Im portantly, our work establishes that the incident energy dependence of R IX S spectra of correlated m aterials is critical inform ation that needs to be carefully

considered in future experim ents and theory, and it calls for the use of a multi-band theoretical approach.

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